*Click **here** for production status of specific part numbers.*

MAX14434–MAX14436

Four-Channel, Fast, Low-Power, 5kV$_{RMS}$ Digital Isolators

General Description

The MAX14434–MAX14436 are the fastest, lowest power, 4-channel, digital galvanic isolators on the market today using Maxim's proprietary process technology. These devices transfer digital signals between circuits with different power domains while using as little as 0.58mW per channel at 1Mbps with a 1.8V supply. The MAX14434/5/6 have an isolation rating of 5kV$_{RMS}$ for 60 seconds.

The MAX14434–MAX14436 family offers all three possible unidirectional channel configurations to accommodate any 4-channel design, including SPI, RS-232, RS-485, and digital I/O applications. Output enable for the A side of the MAX14435R/S/U/V is active-low, making them ideal for isolating a port on a shared SPI bus since the CS signal can directly enable the MISO signal on the isolator. All other devices in the family have the traditional active-high enable.

Devices are available with a maximum data rate of either 25Mbps or 200Mbps and with outputs that are either default-high or default-low. The default is the state the output assumes when the input is either not powered or is open-circuit. See the ***Ordering Information*** for suffixes associated with each option. Independent 1.71V to 5.5V supplies on each side of the isolator also make the devices suitable for use as level translators.

The MAX14434–MAX14436 are available in a 16-pin wide-body SOIC package with 8mm of creepage and clearance. The package material has a minimum comparative tracking index (CTI) of 600V, which gives it a group 1 rating in creepage tables. All devices are rated for operation at ambient temperatures of -40°C to +125°C.

Benefits and Features

- Robust Galvanic Isolation for Fast Digital Signals
  - 200Mbps Data Rate
  - Withstands 5kV$_{RMS}$ for 60s (V$_{ISO}$)
  - Continuously Withstands 848V$_{RMS}$ (V$_{IOWM}$)
  - Withstands ±10kV Surge between GNDA and GNDB with 1.2/50µs waveform
  - High CMTI (50kV/µs, Typical)
- Low Power Consumption
  - 1.1mW per Channel at 1Mbps with V$_{DD}$ = 3.3V
  - 3.5mW per Channel at 100Mbps with V$_{DD}$ = 1.8V
- Options to Support a Broad Range of Applications
  - 2 Data Rates (25Mbps, 200Mbps)
  - 3 Channel Direction Configurations
  - 2 Output Default States (High/Low)

Applications

- Fieldbus Communications for Industrial Automation
- Isolated RS-485/RS-422, CAN
- General Isolation Application
- Battery Management
- Medical Systems

Safety Regulatory Approvals

- UL According to UL1577
- cUL According to CSA Bulletin 5A

***Ordering Information** appears at end of data sheet.*

19-100102; Rev 5; 12/19

maxim integrated™

Absolute Maximum Ratings

V_{DDA} to GNDA ..... -0.3V to +6V
V_{DDB} to GNDB ..... -0.3V to +6V
IN_, EN_ on Side A to GNDA ..... -0.3V to +6V
IN_, EN_ on Side B to GNDB ..... -0.3V to +6V
OUT_ on Side A to GNDA ..... -0.3V to (V_{DDA} + 0.3V)
OUT_ on Side B to GNDB ..... -0.3V to (V_{DDB} + 0.3V)
Short-Circuit Duration
OUT_ on Side A to GNDA,
OUT_ on Side B to GNDB ..... Continuous

Continuous Power Dissipation (T_A = +70°C)
Wide SOIC (derate 14.1mW/°C above +70°C) 1126.8mW
Operating Temperature Range ..... -40°C to +125°C
Maximum Junction Temperature ..... +150°C
Storage Temperature Range ..... -60°C to +150°C
Soldering Temperature (reflow) ..... +260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

PACKAGE TYPE: 16 WIDE SOIC	
Package Code	W16MS+12
Outline Number	**21-0042**
Land Pattern Number	**90-0107**
THERMAL RESISTANCE, FOUR-LAYER BOARD	
Junction to Ambient (θ_{JA})	71°C/W
Junction to Case (θ_{JC})	24°C/W

For the latest package outline information and land patterns (footprints), go to **www.maximintegrated.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to **www.maximintegrated.com/thermal-tutorial**.

DC Electrical Characteristics

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
Supply Voltage	V_{DDA}	Relative to GNDA	1.71		5.5	V
	V_{DDB}	Relative to GNDB	1.71		5.5	
Undervoltage-Lockout Threshold	$V_{UVLO_}$	$V_{DD_}$ rising	1.5	1.6	1.66	V
Undervoltage-Lockout Threshold Hysteresis	V_{UVLO_HYST}			45		mV

DC Electrical Characteristics (continued)

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Current (MAX14434_) (Note 2)	I_{DDA}	500kHz square wave, C_L = 0pF	V_{DDA} = 5V		0.52	0.96	mA
			V_{DDA} = 3.3V		0.51	0.93	
			V_{DDA} = 2.5V		0.50	0.92	
			V_{DDA} = 1.8V		0.49	0.64	
		12.5MHz square wave, C_L = 0pF	V_{DDA} = 5V		1.63	2.42	
			V_{DDA} = 3.3V		1.59	2.36	
			V_{DDA} = 2.5V		1.58	2.33	
			V_{DDA} = 1.8V		1.54	2.00	
		50MHz square wave, C_L = 0pF	V_{DDA} = 5V		4.5	6.14	
			V_{DDA} = 3.3V		4.39	6.00	
			V_{DDA} = 2.5V		4.35	5.93	
			V_{DDA} = 1.8V		4.21	5.43	
Supply Current (MAX14434_) (Note 2)	I_{DDB}	500kHz square wave, C_L = 0pF	V_{DDB} = 5V		0.87	1.47	mA
			V_{DDB} = 3.3V		0.82	1.41	
			V_{DDB} = 2.5V		0.81	1.39	
			V_{DDB} = 1.8V		0.79	1.32	
		12.5MHz square wave, C_L = 0pF	V_{DDB} = 5V		2.97	3.84	
			V_{DDB} = 3.3V		2.00	2.74	
			V_{DDB} = 2.5V		1.69	2.36	
			V_{DDB} = 1.8V		1.43	2.02	
		50MHz square wave, C_L = 0pF	V_{DDB} = 5V		9.52	11.17	
			V_{DDB} = 3.3V		5.68	6.88	
			V_{DDB} = 2.5V		4.45	5.38	
			V_{DDB} = 1.8V		3.46	4.18	
Supply Current (MAX14435_) (Note 2)	I_{DDA}	500kHz square wave, C_L = 0pF	V_{DDA} = 5V		0.62	1.10	mA
			V_{DDA} = 3.3V		0.60	1.06	
			V_{DDA} = 2.5V		0.59	1.05	
			V_{DDA} = 1.8V		0.57	0.83	
		12.5MHz square wave, C_L = 0pF	V_{DDA} = 5V		1.98	2.80	
			V_{DDA} = 3.3V		1.70	2.47	
			V_{DDA} = 2.5V		1.61	2.35	
			V_{DDA} = 1.8V		1.52	2.02	
		50MHz square wave, C_L = 0pF	V_{DDA} = 5V		5.77	7.43	
			V_{DDA} = 3.3V		4.73	6.25	
			V_{DDA} = 2.5V		4.38	5.81	
			V_{DDA} = 1.8V		4.03	5.15	

DC Electrical Characteristics (continued)

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Current (MAX14435_) (Note 2)	I_{DDB}	500kHz square wave, C_L = 0pF	V_{DDB} = 5V		0.78	1.35	mA
			V_{DDB} = 3.3V		0.75	1.30	
			V_{DDB} = 2.5V		0.74	1.28	
			V_{DDB} = 1.8V		0.72	1.16	
		12.5MHz square wave, C_L = 0pF	V_{DDB} = 5V		2.64	3.49	
			V_{DDB} = 3.3V		1.90	2.65	
			V_{DDB} = 2.5V		1.66	2.36	
			V_{DDB} = 1.8V		1.46	2.03	
		50MHz square wave, C_L = 0pF	V_{DDB} = 5V		8.26	9.91	
			V_{DDB} = 3.3V		5.36	6.66	
			V_{DDB} = 2.5V		4.42	5.52	
			V_{DDB} = 1.8V		3.66	4.51	
Supply Current (MAX14436_) (Note 2)	I_{DDA}	500kHz square wave, C_L = 0pF	V_{DDA} = 5V		0.70	1.22	mA
			V_{DDA} = 3.3V		0.67	1.17	
			V_{DDA} = 2.5V		0.66	1.16	
			V_{DDA} = 1.8V		0.64	0.99	
		12.5MHz square wave, C_L = 0pF	V_{DDA} = 5V		2.31	3.15	
			V_{DDA} = 3.3V		1.81	2.56	
			V_{DDA} = 2.5V		1.64	2.35	
			V_{DDA} = 1.8V		1.50	2.02	
		50MHz square wave, C_L = 0pF	V_{DDA} = 5V		7.04	8.70	
			V_{DDA} = 3.3V		5.06	6.46	
			V_{DDA} = 2.5V		4.40	5.67	
			V_{DDA} = 1.8V		3.85	4.83	
	I_{DDB}	500kHz square wave, C_L = 0pF	V_{DDB} = 5V		0.70	1.24	mA
			V_{DDB} = 3.3V		0.67	1.19	
			V_{DDB} = 2.5V		0.66	1.17	
			V_{DDB} = 1.8V		0.65	1.00	
		12.5MHz square wave, C_L = 0pF	V_{DDB} = 5V		2.31	3.15	
			V_{DDB} = 3.3V		1.80	2.57	
			V_{DDB} = 2.5V		1.64	2.36	
			V_{DDB} = 1.8V		1.49	2.03	
		50MHz square wave, C_L = 0pF	V_{DDB} = 5V		7.01	8.66	
			V_{DDB} = 3.3V		5.04	6.46	
			V_{DDB} = 2.5V		4.40	5.67	
			V_{DDB} = 1.8V		3.84	4.83	

DC Electrical Characteristics (continued)

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
LOGIC INPUTS AND OUTPUTS							
Input High Voltage	V_{IH}	EN_, IN_, relative to GND_	2.25V ≤ $V_{DD_}$ ≤ 5.5V	0.7 x $V_{DD_}$			V
		EN_, IN_, relative to GND_	1.71V ≤ $V_{DD_}$ < 2.25V	0.75 x $V_{DD_}$			
Input Low Voltage	V_{IL}	EN_, IN_, relative to GND_	2.25V ≤ $V_{DD_}$ ≤ 5.5V			0.8	V
		EN_, IN_, relative to GND_	1.71V ≤ $V_{DD_}$ < 2.25V			0.7	
Input Hysteresis	V_{HYS}	EN_, IN_, relative to GND_	MAX1443_ B/E/R/U		410		mV
		EN_, IN_, relative to GND_	MAX1443_C/F/S/V		80		
Input Pullup Current (Note 3)	I_{PU}	IN_, MAX1443_B/C/R/S		-10	-5	-1.5	µA
Input Pulldown Current (Note 3)	I_{PD}	IN_, MAX1443_E/F/U/V		1.5	5	10	µA
EN Pullup Current (Note 3)	I_{PU_EN}	EN_		-10	-5	-1.5	µA
Input Capacitance	C_{IN}	IN_, f_{SW} = 1MHz			2		pF
Output Voltage High (Note 3)	V_{OH}	$V_{OUT_}$ relative to GND_ $I_{OUT_}$ = 4mA source		$V_{DD_}$ - 0.4			V
Output Voltage Low (Note 3)	V_{OL}	$V_{OUT_}$ relative to GND_ $I_{OUT_}$ = 4mA sink				0.4	V

Dynamic Characteristics MAX1443_C/F/S/V

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Common-Mode Transient Immunity	CMTI	IN_ = GND_ or $V_{DD_}$ (Note 4)			50		kV/µs
Maximum Data Rate	DR_{MAX}	2.25V ≤ $V_{DD_}$ ≤ 5.5V		200			Mbps
		1.71V ≤ $V_{DD_}$ ≤ 1.89V		150			
Minimum Pulse Width	PW_{MIN}	IN_ to OUT_	2.25V ≤ $V_{DD_}$ ≤ 5.5V			5	ns
			1.71V ≤ $V_{DD_}$ ≤ 1.89V			6.67	
Propagation Delay (Figure 1)	t_{PLH}	IN_ to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V	4.1	5.4	9.2	ns
			3.0V ≤ $V_{DD_}$ ≤ 3.6V	4.2	5.9	10.2	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V	4.9	7.1	13.4	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V	7.1	10.9	20.3	
	t_{PHL}	IN_ to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V	4.3	5.6	9.4	
			3.0V ≤ $V_{DD_}$ ≤ 3.6V	4.4	6.2	10.5	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V	5.1	7.3	14.1	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V	7.2	10.9	21.7	
Pulse Width Distortion	PWD	$\lvert t_{PLH} - t_{PHL} \rvert$			0.3	2	ns
Propagation Delay Skew Part-to-Part (Same Channel)	t_{SPLH}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				3.7	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				4.3	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				6	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				10.3	
	t_{SPHL}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				3.8	
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				4.7	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				6.5	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				11.5	
Propagation Delay Skew Channel-to-Channel (Same Direction)	t_{SCSLH}	1.71V ≤ $V_{DD_}$ ≤ 5.5V				1.5	ns
	t_{SCSHL}	1.71V ≤ $V_{DD_}$ ≤ 5.5V				1.5	

Dynamic Characteristics MAX1443_C/F/S/V (continued)

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Propagation Delay Skew Channel-to-Channel (Opposite Direction)	t_{SCOLH}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				2.9	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				3.4	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				4.9	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				10.2	
	t_{SCOHL}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				3.2	
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				3.8	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				5.3	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				10.9	
Peak Eye Diagram Jitter	$T_{JIT(PK)}$	200Mbps			90		ps
Clock Jitter RMS	$T_{JCLK(RMS)}$	500kHz Clock Input, Rising/Falling Edges			6.5		ps
Rise Time	t_R	4.5V ≤ $V_{DD_}$ ≤ 5.5V				1.6	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				2.2	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				3	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				4.5	
Fall Time	t_F	4.5V ≤ $V_{DD_}$ ≤ 5.5V				1.4	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				2	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				2.8	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				5.1	
Enable to Data Valid	t_{EN}	ENA to OUT_, ENB to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V			3.5	ns
			3.0V ≤ $V_{DD_}$ ≤ 3.6V			5.8	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V			9.3	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V			17.4	
Enable to Tristate	t_{TRI}	ENA to OUT_, ENB to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V			6.4	ns
			3.0V ≤ $V_{DD_}$ ≤ 3.6V			9.2	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V			12.8	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V			19.4	

Dynamic Characteristics MAX1443_B/E/R/U

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Common-Mode Transient Immunity	CMTI	IN_ = GND_ or $V_{DD_}$ (Note 4)			50		kV/µs
Maximum Data Rate	DR_{MAX}			25			Mbps
Minimum Pulse Width	PW_{MIN}	IN_ to OUT_				40	ns
Glitch Rejection		IN_ to OUT_		10	17	29	ns
Propagation Delay (Figure 1)	t_{PLH}	IN_ to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V	17.4	23.9	32.5	ns
			3.0V ≤ $V_{DD_}$ ≤ 3.6V	17.6	24.4	33.7	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V	18.3	25.8	36.7	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V	20.7	29.6	43.5	
	t_{PHL}	IN_ to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V	16.9	23.4	33.6	
			3.0V ≤ $V_{DD_}$ ≤ 3.6V	17.2	24.2	35.1	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V	17.8	25.4	38.2	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V	19.8	29.3	45.8	
Pulse Width Distortion	PWD	$\lvert t_{PLH} - t_{PHL} \rvert$			0.4	4	ns
Propagation Delay Skew Part-to-Part (Same Channel)	t_{SPLH}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				15.1	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				15	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				15.4	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				20.5	
	t_{SPHL}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				13.9	
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				14.2	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				16	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				21.8	
Propagation Delay Skew Channel-to-Channel (Same Direction)	t_{SCSLH}	1.71V ≤ $V_{DD_}$ ≤ 5.5V				2	ns
	t_{SCSHL}	1.71V ≤ $V_{DD_}$ ≤ 5.5V				2	
Propagation Delay Skew Channel-to-Channel (Opposite Direction)	t_{SCOLH}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				13.9	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				13.7	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				14.2	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				19.4	
	t_{SCOHL}	4.5V ≤ $V_{DD_}$ ≤ 5.5V				13	
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				12.9	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				14.4	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				20.1	

Dynamic Characteristics MAX1443_B/E/R/U (continued)

(V_{DDA} - V_{GNDA} = 1.71V to 5.5V, V_{DDB} - V_{GNDB} = 1.71V to 5.5V, C_L = 15pF, T_A = -40°C to +125°C, unless otherwise noted. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Peak Eye Diagram Jitter	$T_{JIT(PK)}$	25Mbps			250		ps
Rise Time (Figure 1)	t_R	4.5V ≤ $V_{DD_}$ ≤ 5.5V				1.6	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				2.2	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				3	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				4.5	
Fall Time (Figure 1)	t_F	4.5V ≤ $V_{DD_}$ ≤ 5.5V				1.4	ns
		3.0V ≤ $V_{DD_}$ ≤ 3.6V				2	
		2.25V ≤ $V_{DD_}$ ≤ 2.75V				2.8	
		1.71V ≤ $V_{DD_}$ ≤ 1.89V				5.1	
Enable to Data Valid	t_{EN}	ENA to OUT_, ENB to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V			3.5	ns
			3.0V ≤ $V_{DD_}$ ≤ 3.6V			5.8	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V			9.3	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V			17.4	
Enable to Tristate	t_{TRI}	ENA to OUT_, ENB to OUT_, C_L = 15pF	4.5V ≤ $V_{DD_}$ ≤ 5.5V			6.4	ns
			3.0V ≤ $V_{DD_}$ ≤ 3.6V			9.2	
			2.25V ≤ $V_{DD_}$ ≤ 2.75V			12.8	
			1.71V ≤ $V_{DD_}$ ≤ 1.89V			19.4	

Note 1: All devices are 100% production tested at T_A = +25°C. Specifications over temperature are guaranteed by design.
Note 2: Not production tested. Guaranteed by design and characterization,
Note 3: All currents into the device are positive. All currents out of the device are negative. All voltages are referenced to their respective ground (GNDA or GNDB), unless otherwise noted.
Note 4: CMTI is the maximum sustainable common-mode voltage slew rate while maintaining the correct output. CMTI applies to both rising and falling common-mode voltage edges. Tested with the transient generator connected between GNDA and GNDB (V_{CM} = 1000V).

ESD Protection

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ESD		Human Body Model, All Pins		±4		kV

Safety Regulatory Approvals

UL
The MAX14434–MAX14436 are certified under UL1577. For more details, refer to File E351759.
Rated up to 5000V$_{RMS}$ isolation voltage for single protection.
cUL (Equivalent to CSA notice 5A)
The MAX14434–MAX14436 are certified up to 5000V$_{RMS}$ for single protection. For more details, refer to File 351759.

Table 1. Insulation Characteristics

PARAMETER	SYMBOL	CONDITIONS	VALUE	UNITS
Partial Discharge Test Voltage	V_{PR}	Method B1 = V_{IORM} x 1.875 (t = 1s, partial discharge < 5pC)	2250	V_P
Maximum Repetitive Peak Isolation Voltage	V_{IORM}	(Note 5)	1200	V_P
Maximum Working Isolation Voltage	V_{IOWM}	Continuous RMS voltage (Note 5)	848	V_{RMS}
Maximum Transient Isolation Voltage	V_{IOTM}	t = 1s	8400	V_P
Maximum Withstand Isolation Voltage	V_{ISO}	f_{SW} = 60Hz, duration = 60s (Note 6)	5000	V_{RMS}
Maximum Surge Isolation Voltage	V_{IOSM}	Basic Insulation, 1.2/50µs pulse per IEC61000-4-5	10	kV
Insulation Resistance	R_S	V_{IO} = 500V	>10^{12}	Ω
Barrier Capacitance Side A to Side B	CIO	f_{SW} = 1MHz (Note 7)	2	pF
Minimum Creepage Distance	CPG		8	mm
Minimum Clearance Distance	CLR		8	mm
Internal Clearance		Distance through insulation	0.015	mm
Comparative Tracking Index	CTI	Material Group I (IEC 60112)	>600	
Climate Category			40/125/21	
Pollution Degree (DIN VDE 0110, Table 1)			2	

Note 5: V_{ISO}, V_{IOWM}, and V_{IORM} are defined by the IEC 60747-5-5 standard.
Note 6: Product is qualified at V_{ISO} for 60s and 100% production tested at 120% of V_{ISO} for 1s.
Note 7: Capacitance is measured with all pins on field-side and logic-side tied together.

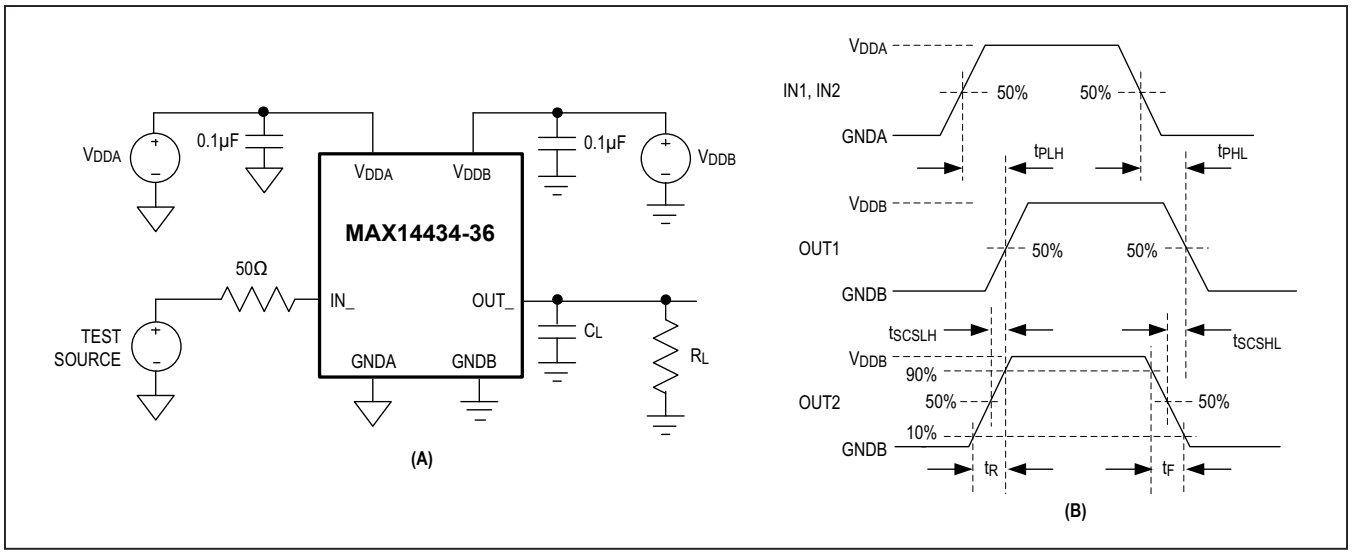
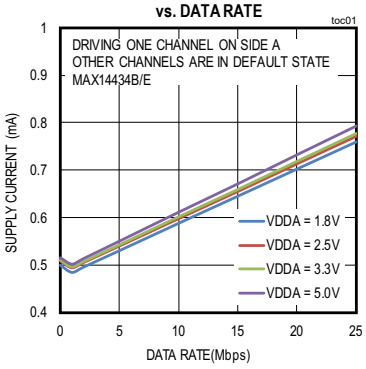


Figure 1. Test Circuit (A) and Timing Diagram (B)

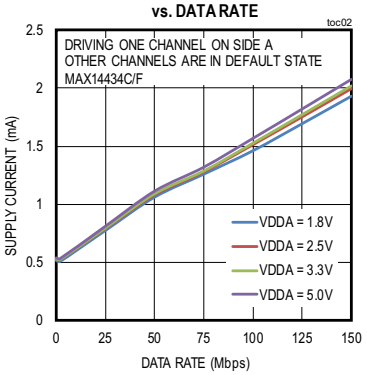
Typical Operating Characteristics

(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.)

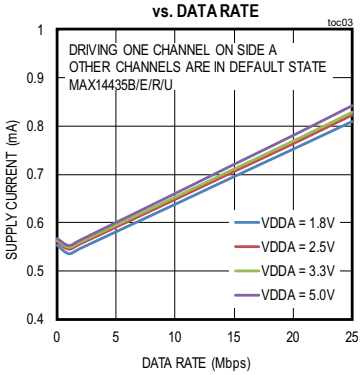
SIDE A SUPPLY CURRENT vs. DATA RATE



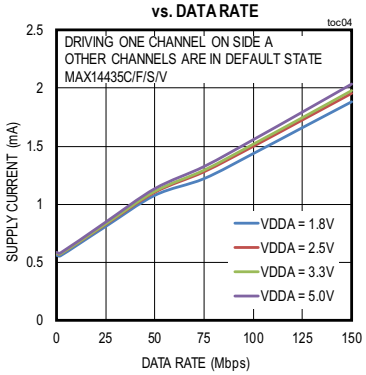
SIDE A SUPPLY CURRENT vs. DATA RATE



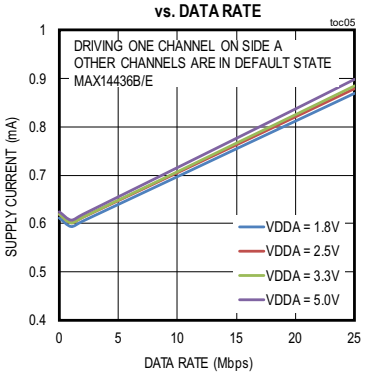
SIDE A SUPPLY CURRENT vs. DATA RATE



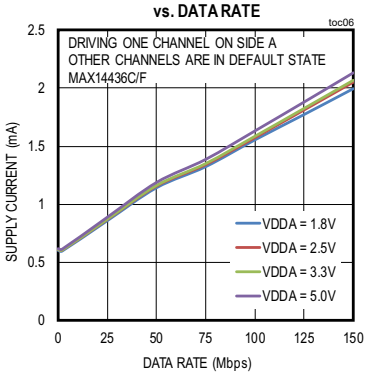
SIDE A SUPPLY CURRENT vs. DATA RATE



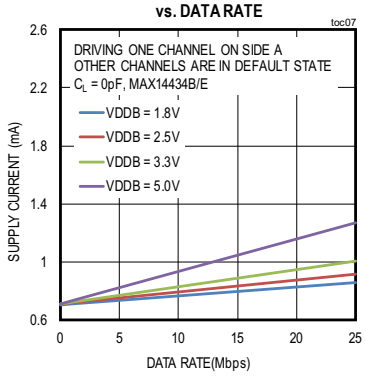
SIDE A SUPPLY CURRENT vs. DATA RATE



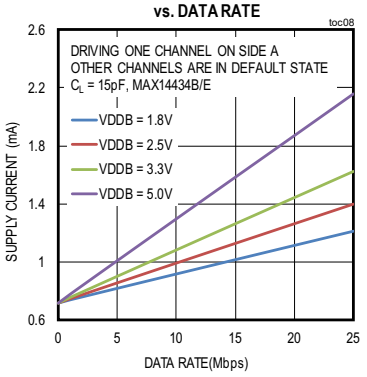
SIDE A SUPPLY CURRENT vs. DATA RATE



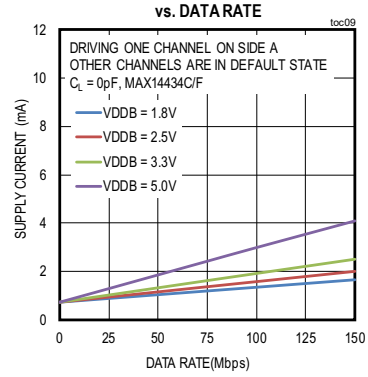
SIDE B SUPPLY CURRENT vs. DATA RATE



SIDE B SUPPLY CURRENT vs. DATA RATE

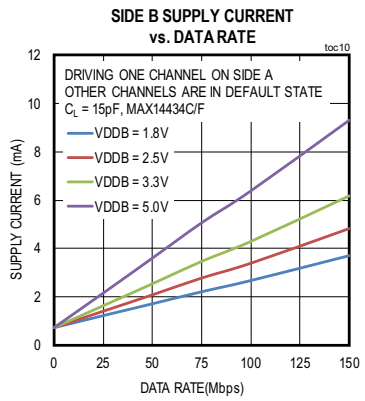


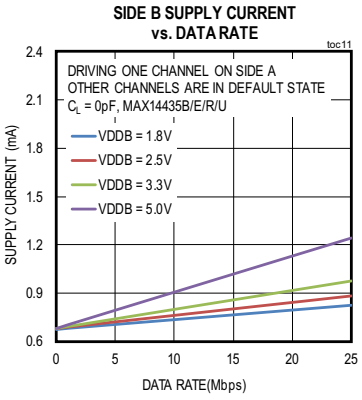
SIDE B SUPPLY CURRENT vs. DATA RATE

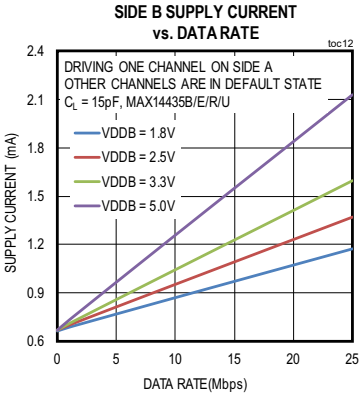


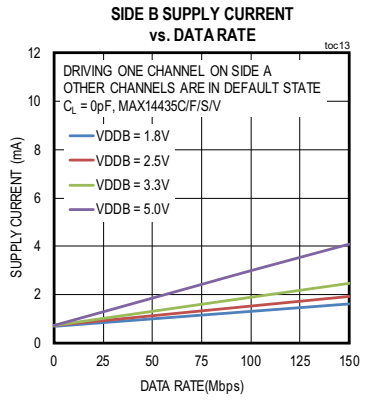
Typical Operating Characteristics (continued)

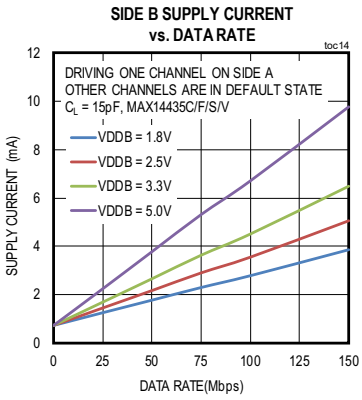
(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.)

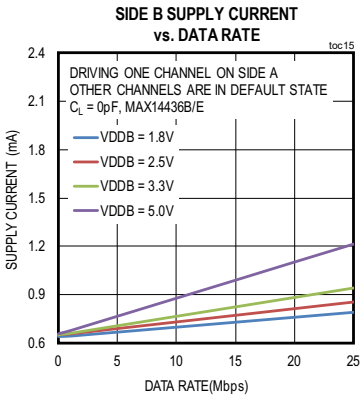


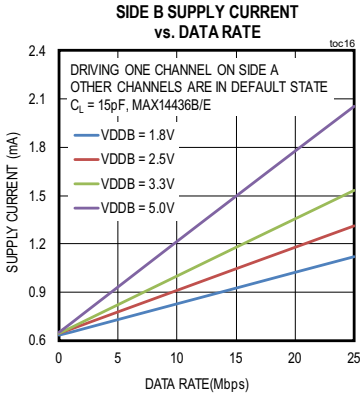


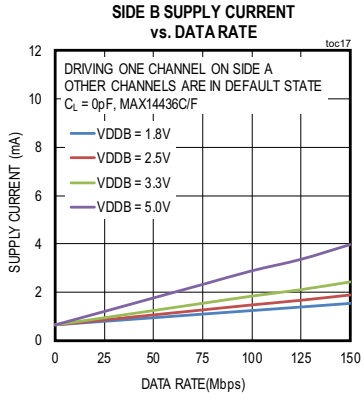


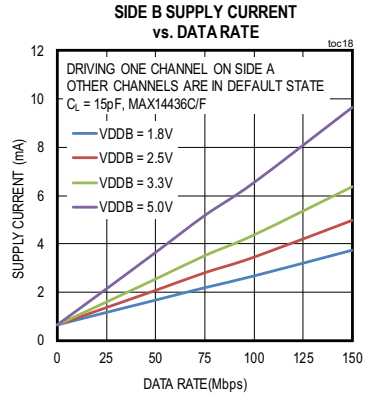








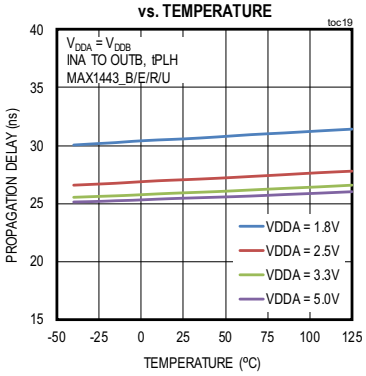




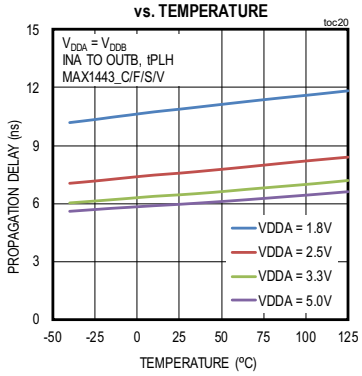
Typical Operating Characteristics (continued)

(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.)

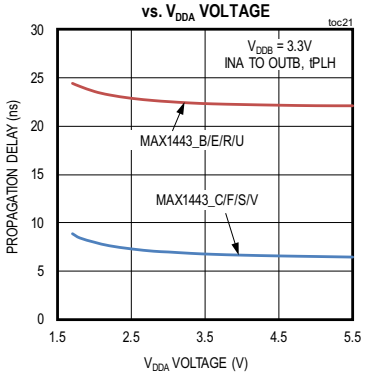
PROPAGATION DELAY vs. TEMPERATURE



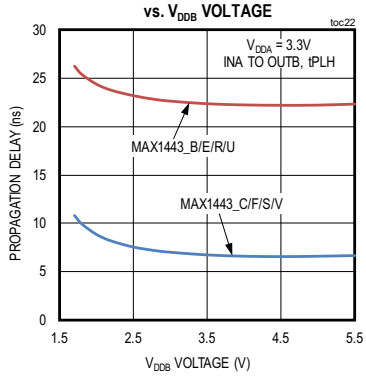
PROPAGATION DELAY vs. TEMPERATURE



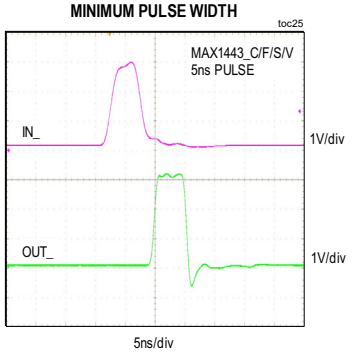
PROPAGATION DELAY vs. V_{DDA} VOLTAGE



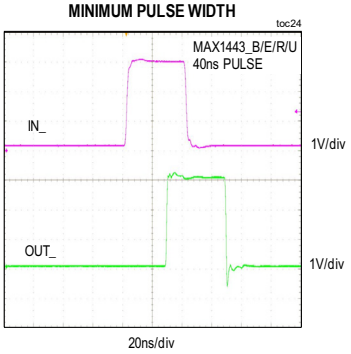
PROPAGATION DELAY vs. V_{DDB} VOLTAGE



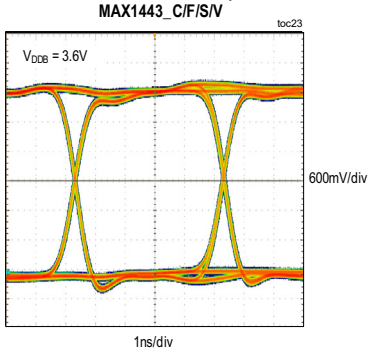
MINIMUM PULSE WIDTH



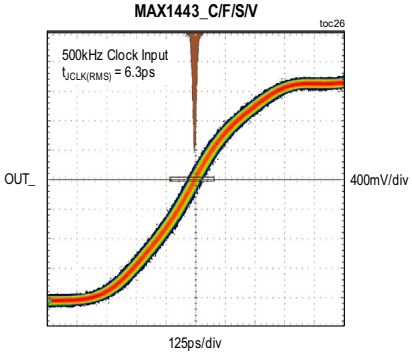
MINIMUM PULSE WIDTH



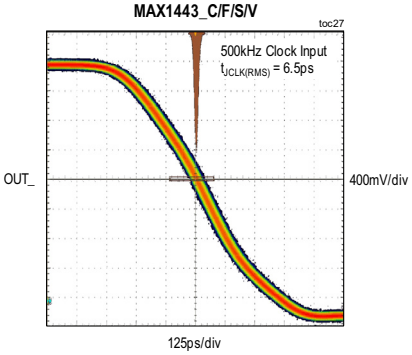
EYE DIAGRAM at 200Mbps MAX1443_C/F/S/V



CLOCK JITTER RMS ON RISING EDGE MAX1443_C/F/S/V

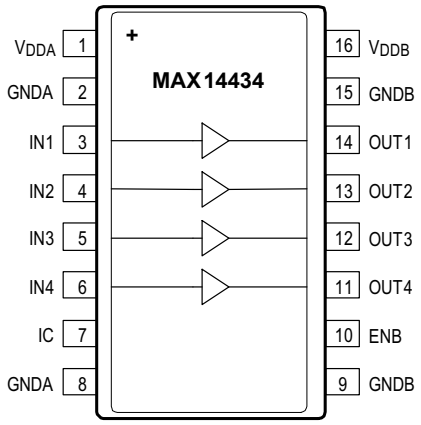


CLOCK JITTER RMS ON FALLING EDGE MAX1443_C/F/S/V

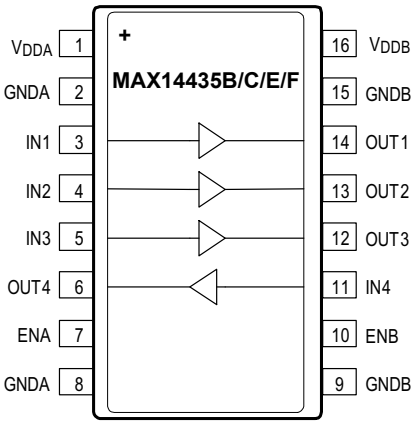


Pin Configurations

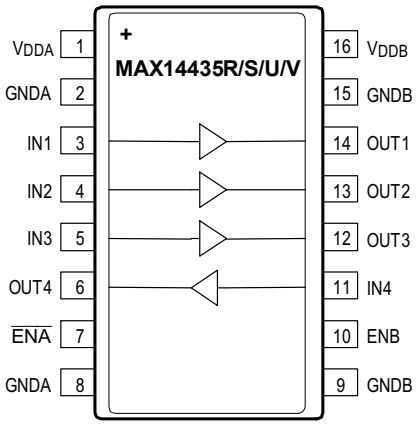
TOP VIEW



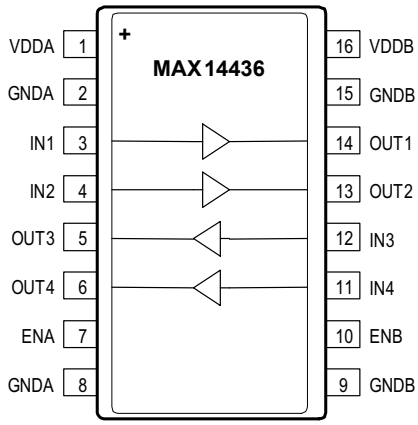
SOIC



SOIC



SOIC

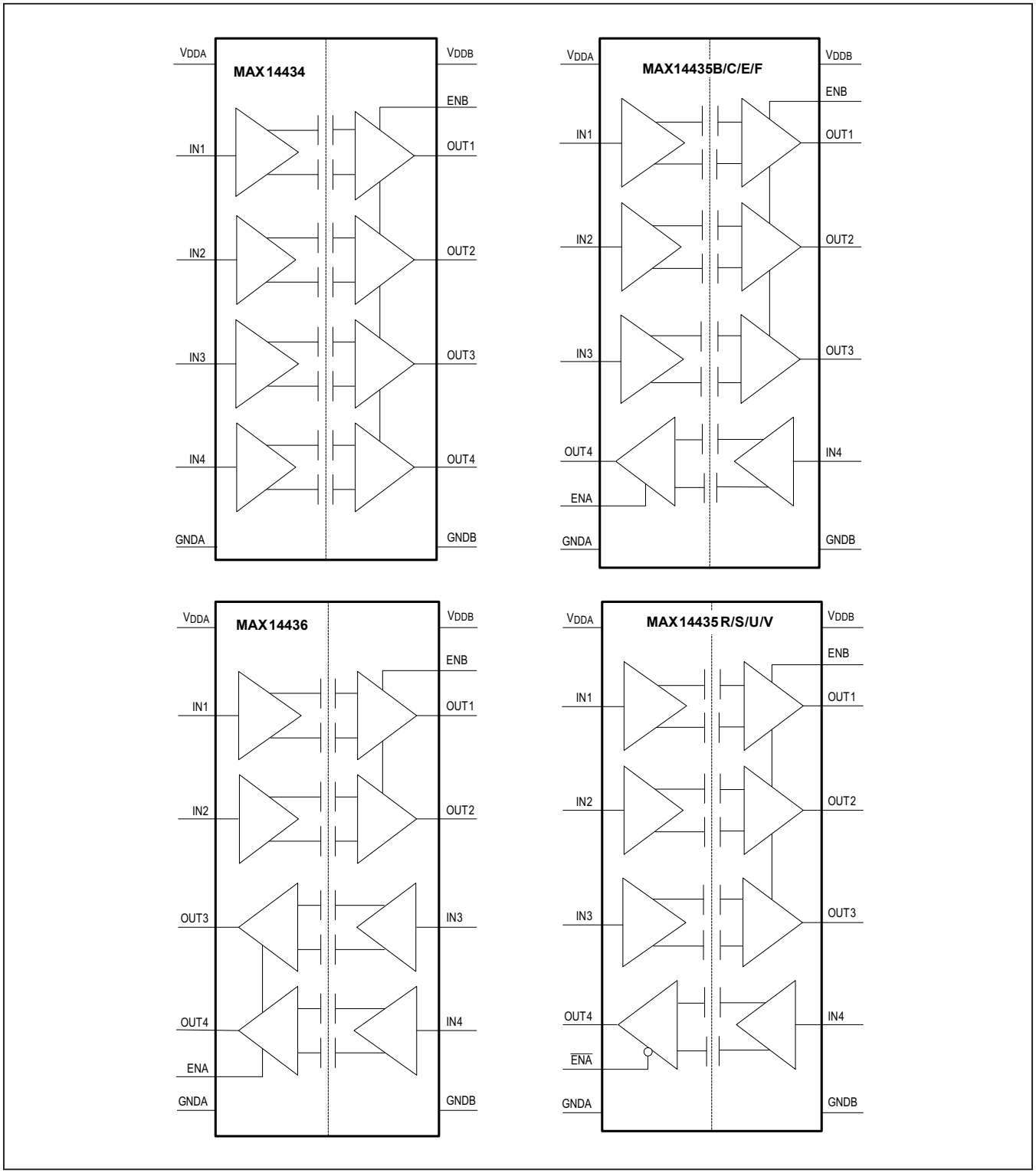


SOIC

Pin Description

NAME	PIN				FUNCTION
	MAX14434	MAX14435B/C/E/F	MAX14435R/S/U/V	MAX14436	
V_{DDA}	1	1	1	1	Power Supply. Bypass V_{DDA} with a 0.1µF ceramic capacitor as close as possible to the pin.
GNDA	2, 8	2, 8	2, 8	2, 8	Ground Reference for Side A
IN1	3	3	3	3	Logic Input 1 on Side A, corresponds to Logic Output 1 on Side B
IN2	4	4	4	4	Logic Input 2 on Side A, corresponds to Logic Output 2 on Side B
IN3	5	5	5	12	Logic Input 3 on Side A or B, corresponds to Logic Output 3 on Side B or A
IN4	6	11	11	11	Logic Input 4 on Side A or B, corresponds to Logic Output 4 on Side B or A
I.C.	7	—	—	—	Internally Connected. Leave unconnected or connect to GNDA or V_{DDA}.
ENA	—	7	—	7	Active-High Enable for Side A. ENA has an internal 5µA pullup to V_{DDA}.
$\overline{ENA}$	—	—	7	—	Active-Low Enable for Side A. $\overline{ENA}$ has an internal 5µA pullup to V_{DDA}
OUT1	14	14	14	14	Logic Output 1 on Side B
OUT2	13	13	13	13	Logic Output 2 on Side B
OUT3	12	12	12	5	Logic Output 3 on Side A or Side B
OUT4	11	6	6	6	Logic Output 4 on Side A or Side B
ENB	10	10	10	10	Active-High Enable for Side B. ENB has an internal 5µA pullup to V_{DDB}.
GNDB	9, 15	9, 15	9, 15	9, 15	Ground Reference for Side B
V_{DDB}	16	16	16	16	Power Supply. Bypass V_{DDB} with a 0.1µF ceramic capacitor as close as possible to the pin.

Functional Diagram



Detailed Description

The MAX14434–MAX14436 is a family of 4-channel digital isolators. The MAX14434–MAX14436 have an isolation rating of 5kV$_{RMS}$. The MAX14434–MAX14436 family offers all three possible unidirectional channel configurations to accommodate any 4-channel design, including SPI, RS-232, RS-485, and digital I/O applications. For applications requiring bidirectional channels, such as I^{2}C, see the MAX14933 and MAX14937.

The MAX14434 features four channels transferring digital signals in one direction for applications such as isolated digital I/O. The MAX14435 has three channels transmitting data in one direction and one channel transmitting in the opposite direction, making it ideal for applications such as isolated SPI and RS-485 communication. The MAX14436 provides further design flexibility with two channels in each direction for isolated RS-232 or other applications.

Devices are available in the 16-pin wide-body SOIC package and are rated for up to 5kV$_{RMS}$. This family of digital isolators offers low-power operation, high electromagnetic interference (EMI) immunity, and stable temperature performance through Maxim's proprietary process technology. The devices isolate different ground domains and block high-voltage/high-current transients from sensitive or human interface circuitry.

Devices are available with a maximum data rate of either 25Mbps (B/E/R/U versions) or 200Mbps (C/F/S/V versions). Each device can be ordered with default-high or default-low outputs. The default is the state the output assumes when the input is not powered or if the input is open circuit. The devices have two supply inputs (V_{DDA} and V_{DDB}) that independently set the logic levels on either side of the device. V_{DDA} and V_{DDB} are referenced to GNDA and GNDB, respectively. The MAX14434–MAX14436 family also features a refresh circuit to ensure output accuracy when an input remains in the same state indefinitely.

Digital Isolation

The MAX14434–MAX14436 family provides galvanic isolation for digital signals that are transmitted between two ground domains. The devices withstand differences of up to 5kV$_{RMS}$ for up to 60 seconds, and up to 1200V$_{PEAK}$ of continuous isolation.

Level-Shifting

The wide supply voltage range of both V_{DDA} and V_{DDB} allows the MAX14434–MAX14436 family to be used for level translation in addition to isolation. V_{DDA} and V_{DDB} can be independently set to any voltage from 1.71V to 5.5V. The supply voltage sets the logic level on the corresponding side of the isolator.

Unidirectional Channels

Each channel of the MAX14434–MAX14436 is unidirectional; it only passes data in one direction, as indicated in the functional diagram. Each device features four unidirectional channels that operate independently with guaranteed data rates from DC up to 25Mbps (B/E/R/U versions), or from DC to 200Mbps (C/F/S/V versions). The output driver of each channel is push-pull, eliminating the need for pullup resistors. The outputs are able to drive both TTL and CMOS logic inputs.

Startup and Undervoltage-Lockout

The V_{DDA} and V_{DDB} supplies are both internally monitored for undervoltage conditions. Undervoltage events can occur during power-up, power-down, or during normal operation due to a sagging supply voltage. When an undervoltage condition is detected on either supply while the outputs are enabled, all outputs go to their default states regardless of the state of the inputs (Table 2). Figure 2 through Figure 5 show the behavior of the outputs during power-up and power-down.

Table 2. Output Behavior During Undervoltage Conditions

$V_{IN_}$	V_{DDA}	V_{DDB}	ENA	ENB	V_{OUTA}	V_{OUTB}
1	Powered	Powered	1	1	1	1
			0	0	Hi-Z	Hi-Z
0	Powered	Powered	1	1	0	0
			0	0	Hi-Z	Hi-Z
X	Undervoltage	Powered	1	1	Default	Default
			0	0	Hi-Z	Hi-Z
X	Powered	Undervoltage	1	1	Default	Default
			0	0	Hi-Z	Hi-Z

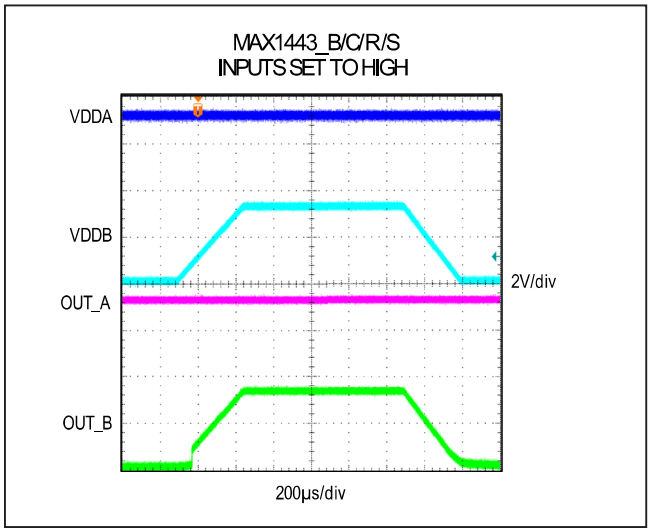


Figure 2. Undervoltage Lockout Behavior (MAX1443_B/C/R/S High)

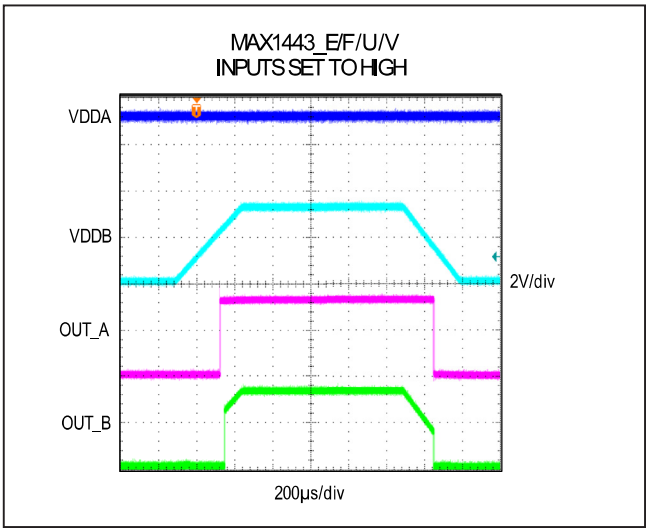


Figure 3. Undervoltage Lockout Behavior (MAX1443_E/F/U/V High)

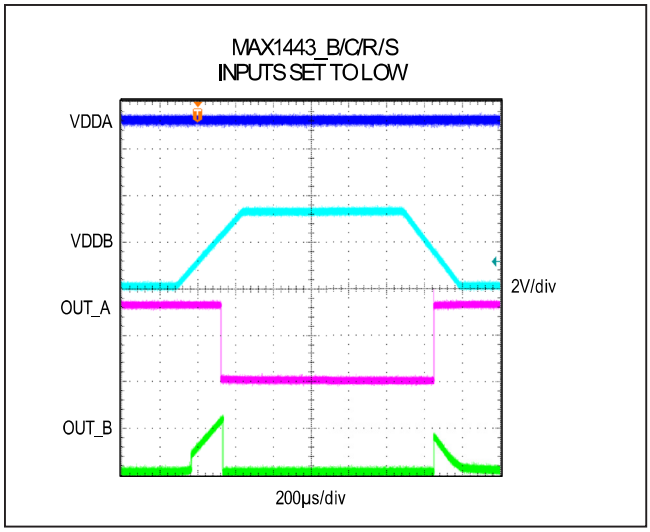


Figure 4. Undervoltage Lockout Behavior (MAX1443_B/C/R/S Low)

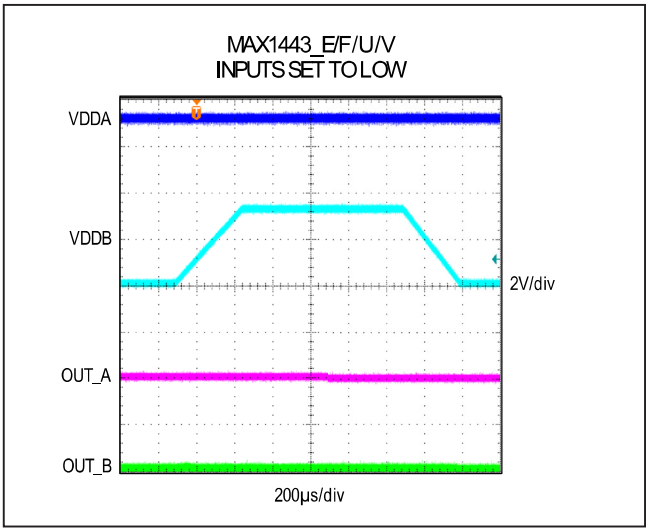


Figure 5. Undervoltage Lockout Behavior (MAX1443_E/F/U/V Low)

Applications Information

Power-Supply Sequencing

The MAX14434–MAX14436 do not require special power supply sequencing. The logic levels are set independently on either side by V_{DDA} and V_{DDB}. Each supply can be present over the entire specified range regardless of the level or presence of the other supply.

Power-Supply Decoupling

To reduce ripple and the chance of introducing data errors, bypass V_{DDA} and V_{DDB} with 0.1µF low-ESR ceramic capacitors to GNDA and GNDB, respectively. Place the bypass capacitors as close to the power supply input pins as possible.

Layout Considerations

The PCB designer should follow some critical recommendations in order to get the best performance from the design.

- Keep the input/output traces as short as possible. Avoid using vias to make low-inductance paths for the signals.
- Have a solid ground plane underneath the high-speed signal layer.
- Keep the area underneath the MAX14434–MAX14436 free from ground and signal planes. Any galvanic or metallic connection between the field-side and logic-side defeats the isolation.

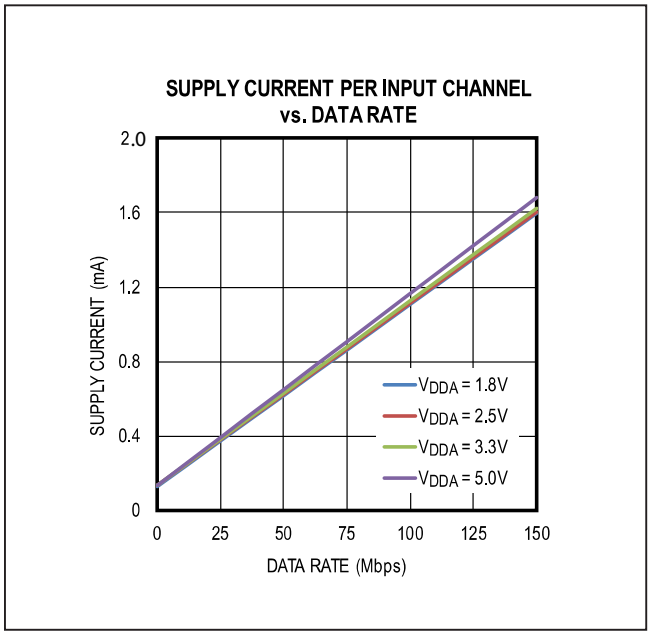


Figure 6. Supply Current Per Input Channel (Estimated)

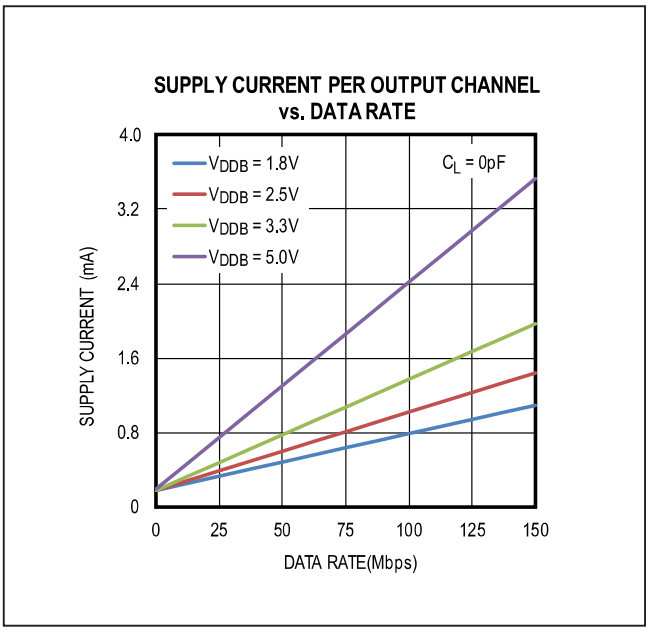


Figure 7. Supply Current Per Output Channel (Estimated)

Calculating Power Dissipation

The required current for a given supply (V_{DDA} or V_{DDB}) can be estimated by summing the current required for each channel. The supply current for a channel depends on whether the channel is an input or an output, the channel's data rate, and the capacitive or resistive load if it is an output. The typical current for an input or output at any data rate can be estimated from the graphs in Figure 6 and Figure 7. Please note the data in Figure 6 and Figure 7 are extrapolated from the supply current measurements in a typical operating condition.

The total current for a single channel is the sum of the "no load" current (shown in Figure 6 and Figure 7) which is a function of Voltage and Data Rate, and the "load current," which depends on the type of load. Current into a capacitive load is a function of the load capacitance, the switching frequency, and the supply voltage.

$$I_{CL} = C_L \times f_{SW} \times V_{DD}$$

where

I_{CL} is the current required to drive the capacitive load.

C_L is the load capacitance on the isolator's output pin.

f_{SW} is the switching frequency (bits per second / 2).

V_{DD} is the supply voltage on the output side of the isolator.

Current into a resistive load depends on the load resistance, the supply voltage and the average duty cycle of the data waveform. The DC load current can be conservatively estimated by assuming the output is always high.

$$I_{RL} = V_{DD} \div R_L$$

where

I_{RL} is the current required to drive the resistive load.

V_{DD} is the supply voltage on the output side of the isolator.

R_L is the load resistance on the isolator's output pin.

Example (shown in Figure 8): A MAX14435F is operating with V_{DDA} = 2.5V, V_{DDB} = 3.3V, channel 1 operating at 20Mbps with a 10pF capacitive load, channel 2 held high with a 10kΩ resistive load, and channel 4 operating at 100Mbps with a 15pF capacitive load. Channel 3 is not in use and the resistive load is negligible since the isolator is driving a CMOS input. Refer to Table 3 and Table 4 for V_{DDA} and V_{DDB} supply current calculation worksheets.

V_{DDA} must supply:

- Channel 1 is an input channel operating at 2.5V and 20Mbps, consuming 0.33mA, estimated from Figure 6.
- Channel 2 and 3 are input channels operating at 2.5V with DC signal, consuming 0.13mA, estimated from Figure 6.
- Channel 4 is an output channel operating at 2.5V and 100Mbps, consuming 1.02mA, estimated from Figure 7.
- I_{CL} on channel 4 for 15pF capacitor at 2.5V and 100Mbps is 1.875mA.

Total current for side A = 0.33 + 0.13 × 2 + 1.02 + 1.875 = 3.485mA, typical

V_{DDB} must supply:

- Channel 1 is an output channel operating at 3.3V and 20Mbps, consuming 0.42mA, estimated from Figure 7.
- Channel 2 and 3 are output channels operating at 3.3V with DC signal, consuming 0.18mA, estimated from Figure 7.
- Channel 4 is an input channel operating at 3.3V and 100Mbps, consuming 1.13mA, estimated from Figure 6.
- I_{CL} on channel 1 for 10pF capacitor at 3.3V and 20Mbps is 0.33mA.
- I_{RL} on channel 2 for 10kΩ resistor held at 3.3V is 0.33mA.

Total current for side B = 0.42 + 0.18 × 2 + 1.13 + 0.33 + 0.33 = 2.57mA, typical

Table 3. Side A Supply Current Calculation Worksheet

SIDE A	V_{DDA} = 2.5V					
Channel	IN/ OUT	Data Rate (Mbps)	Load Type	Load	"No Load" Current (mA)	Load Current (mA)
1	IN	20			0.33	
2	IN	0			0.13	
3	IN	0			0.13	
4	OUT	100	Capacitive	15pF	1.02	2.5V x 50MHz x 15pF = 1.875mA
Total: 3.485mA						

Table 4. Side B Supply Current Calculation Worksheet

SIDE B	V_{DDB} = 3.3V					
Channel	**IN/ OUT**	**Data Rate (Mbps)**	**Load Type**	**Load**	**"No Load" Current (mA)**	**Load Current (mA)**
1	OUT	20	Capacitive	10pF	0.42	3.3V x 10MHz x 10pF = 0.33mA
2	OUT	0	Resistive	10kΩ	0.18	3.3V / 10kΩ = 0.33mA
3	OUT	0			0.18	
4	IN	100			1.13	
Total: 2.57mA						

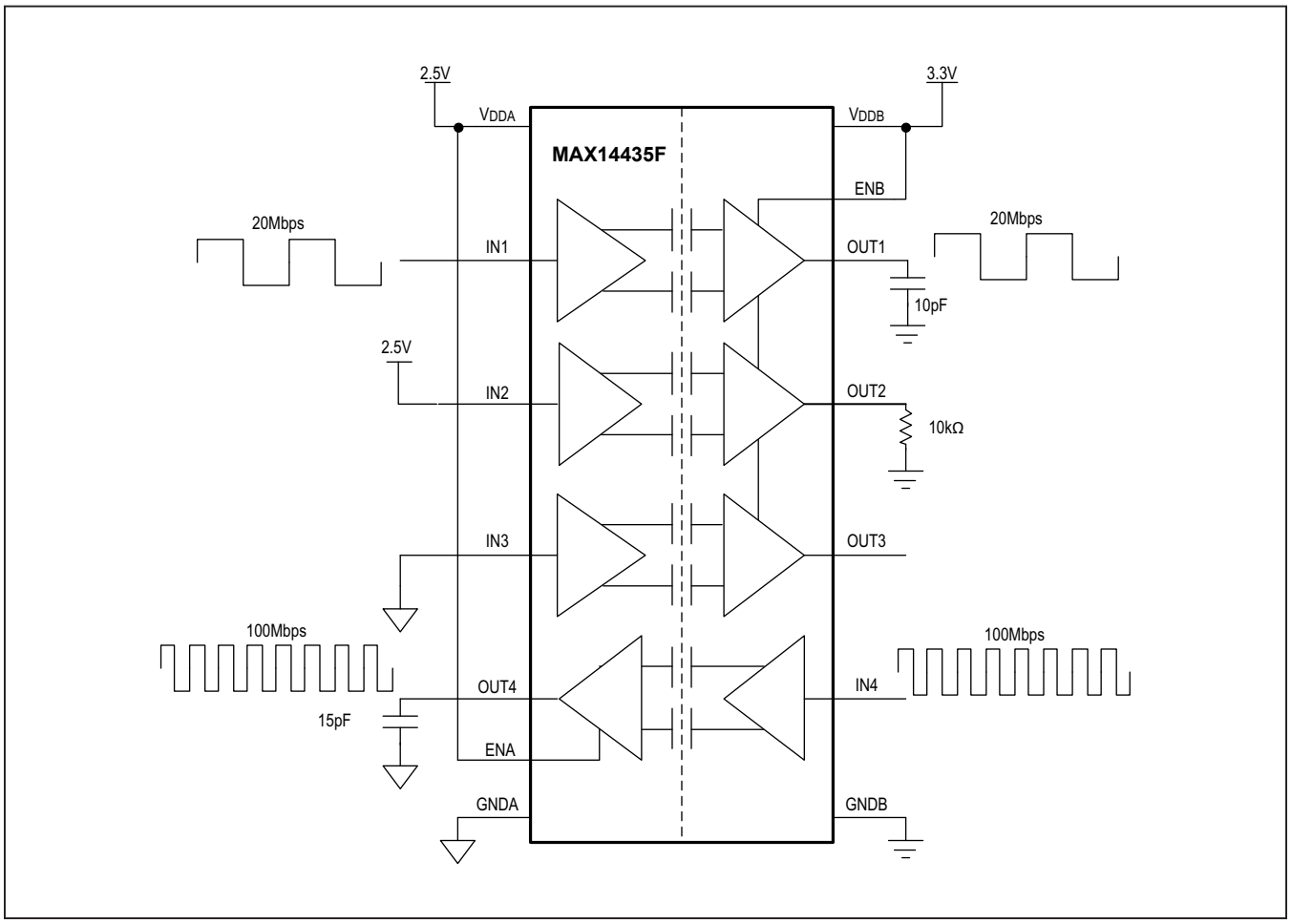
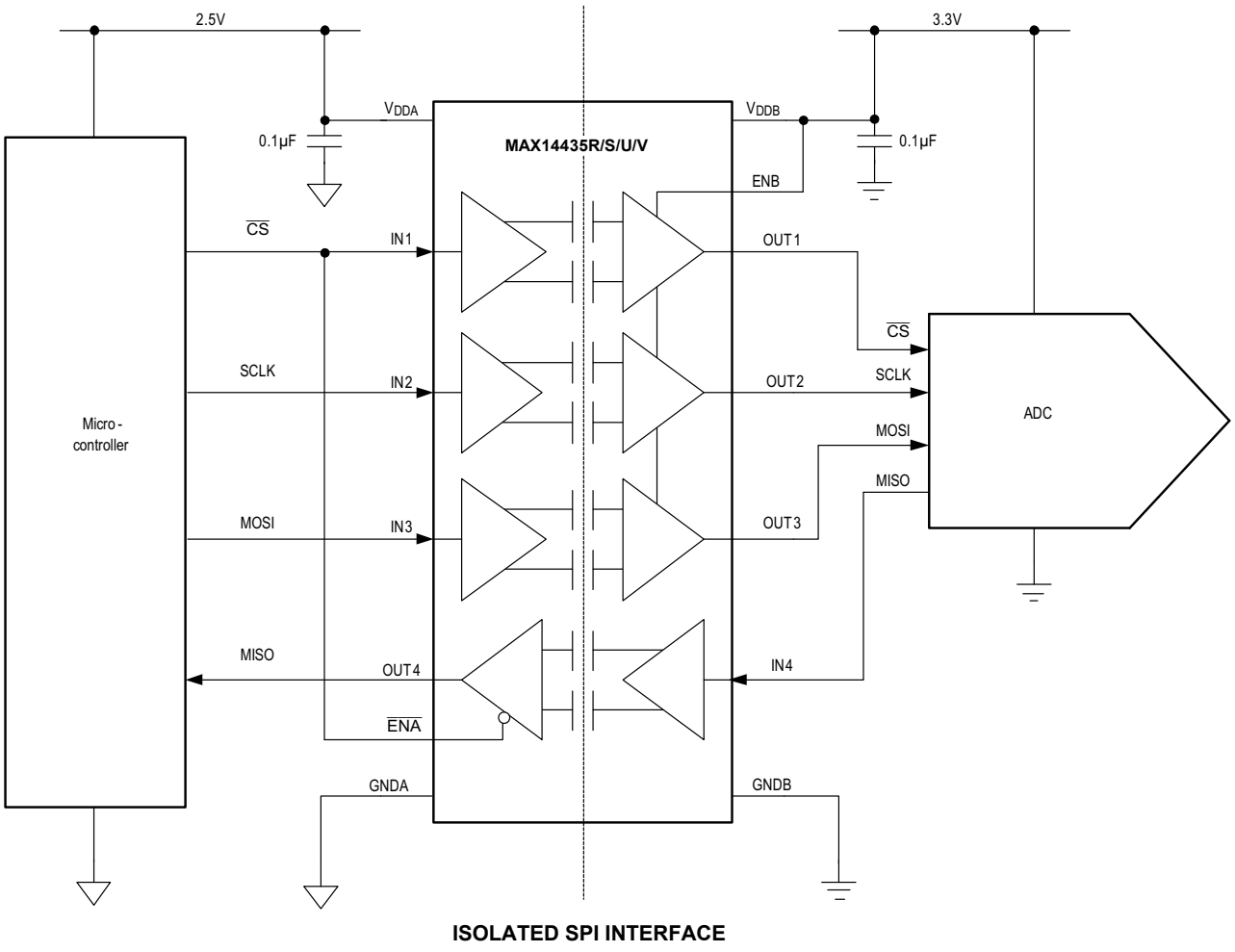


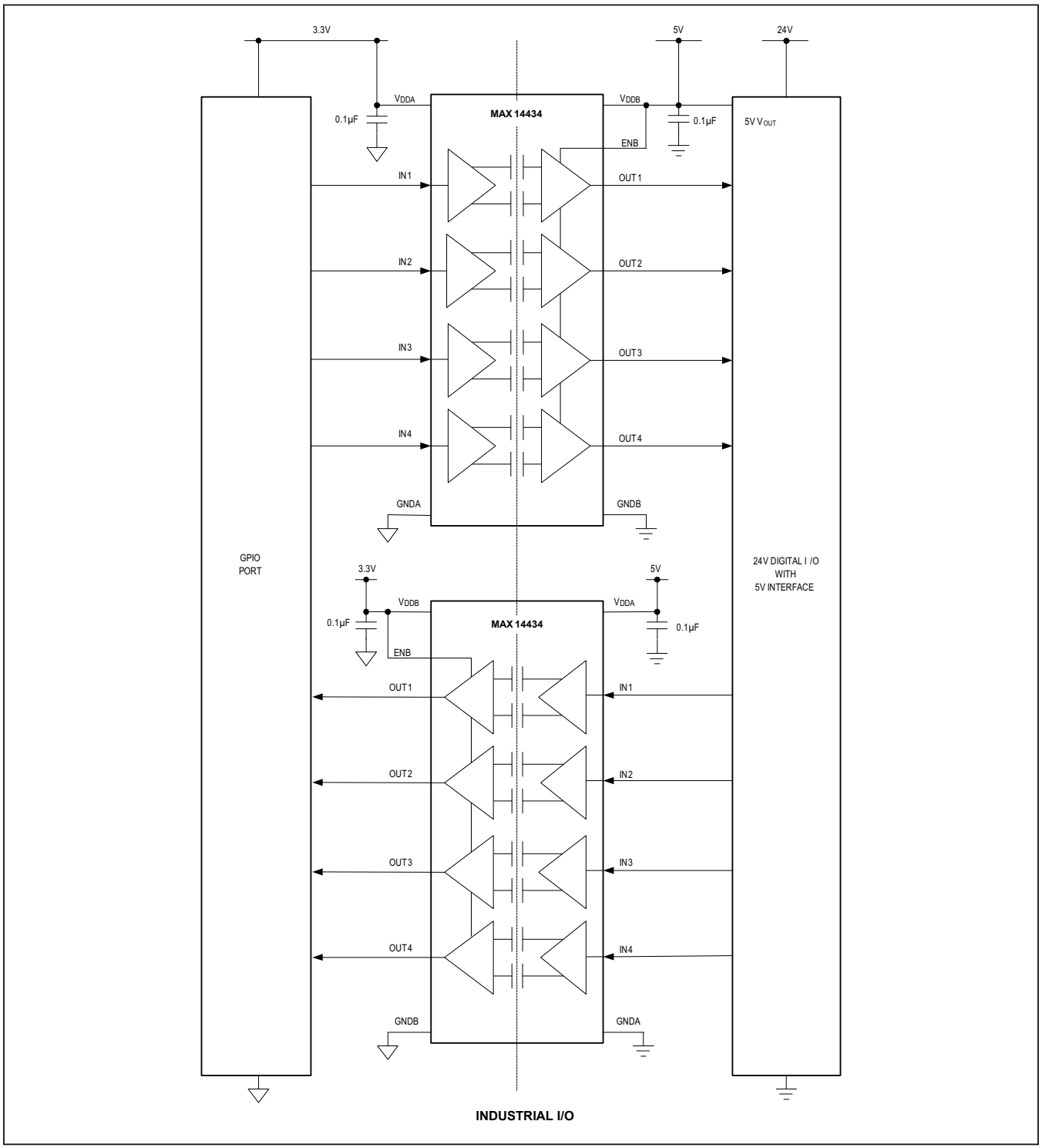
Figure 8. Example Circuit for Supply Current Calculation

Typical Operating Circuit

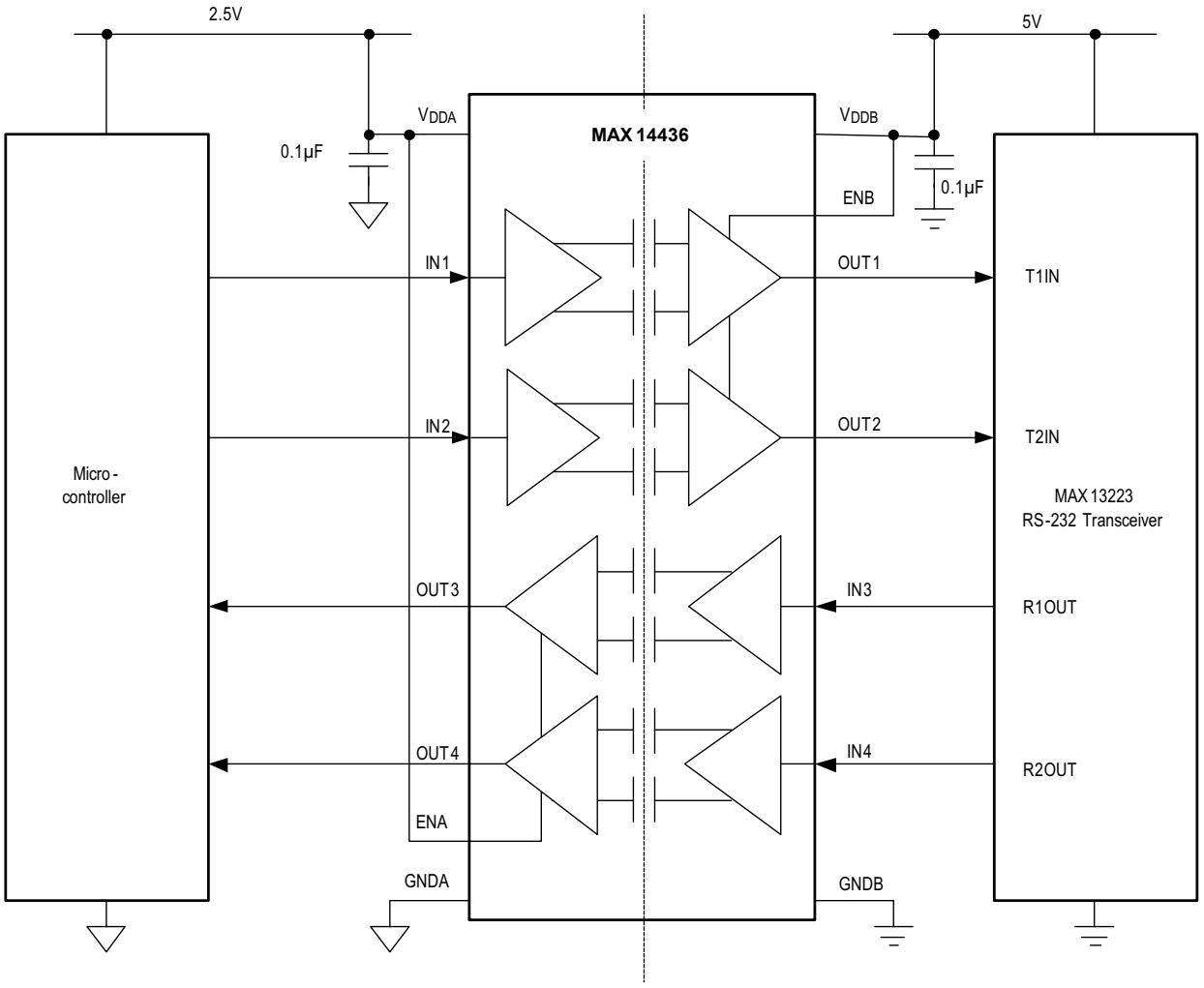


ISOLATED SPI INTERFACE

Typical Operating Circuit (continued)



Typical Operating Circuit (continued)



ISOLATED RS-232

Ordering Information

PART	CHANNEL CONFIGU-RATION	DATA RATE (Mbps)	DEFAULT OUTPUT	ENA Polarity	ISOLATION VOLTAGE (kV$_{RMS}$)	TEMP RANGE (°C)	PIN-PACKAGE
MAX14434BAWE+*	4/0	25	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14434CAWE+*	4/0	200	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14434EAWE+	4/0	25	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14434FAWE+	4/0	200	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435BAWE+*	3/1	25	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435CAWE+*	3/1	200	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435EAWE+*	3/1	25	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435FAWE+	3/1	200	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435RAWE+*	3/1	25	Default High	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14435SAWE+*	3/1	200	Default High	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14435UAWE+*	3/1	25	Default Low	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14435VAWE+*	3/1	200	Default Low	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14436BAWE+*	2/2	25	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14436CAWE+*	2/2	200	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14436EAWE+*	2/2	25	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14436FAWE+	2/2	200	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC

**Future Product—Contact Maxim for availability.*

+Denotes a lead(Pb)-free/RoHS-compliant package.

Chip Information

PROCESS: BiCMOS

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/17	Initial release	—
1	8/17	Updated *Insulation Characteristics* table	10
2	1/18	Updated *Ordering Information* table	25
3	1/19	Removed future product designation from MAX14434FAWE+ in the *Ordering Information* table	24
4	2/19	Updated the *Safety and Regulatory Approvals* section and added the *Safety and Regulatory Approvals* table	1, 9
5	12/19	Removed future product designation from MAX14434EAWE+ in the *Ordering Information* table	25

For pricing, delivery, and ordering information, please visit Maxim Integrated's online storefront at https://www.maximintegrated.com/en/storefront/storefront.html.

Maxim Integrated cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim Integrated product. No circuit patent licenses are implied. Maxim Integrated reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.

Maxim Integrated and the Maxim Integrated logo are trademarks of Maxim Integrated Products, Inc. © 2019 Maxim Integrated Products, Inc.

LifeElectronics
Живое партнерство

ООО «ЛайфЭлектроникс» **“LifeElectronics” LLC**

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- *Конкурентоспособные цены и скидки постоянным клиентам.*
- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*

- *Приемлемые сроки поставки, возможна ускоренная поставка.*
- *Доставку товара в любую точку России и стран СНГ.*
- *Комплексную поставку.*
- *Работу по проектам и поставку образцов.*
- *Формирование склада под заказчика.*

- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
- *Наличие сертификата ISO.*

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- *Регистрацию проекта у производителя компонентов.*
- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru

www.lifeelectronics.ru